Attorney Docket No.: PATENT SSI-00501

## **CLAIMS**

We claim:

i	1.	A high pressure chamber for processing of a semiconductor substrate
2		comprising:
3		a. a chamber housing comprising a first sealing surface;
4		b. a platen comprising a region for holding the semiconductor
5		substrate and a second sealing surface; and
6		c. a mechanical drive mechanism coupling the platen to the chamber
7		housing such that in operation the mechanical drive mechanism separates
8		the platen from the chamber housing for loading of the semiconductor
9		substrate and further such that in operation the mechanical drive
Ď		mechanism causes the second sealing surface of the platen and the first
<b>וְ</b>		sealing surface of the chamber housing to form a high pressure processing
<u></u>		chamber around the semiconductor substrate.
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1	2.	The high pressure chamber of claim 1 wherein the first sealing surface of
		the chamber housing comprises an o-ring groove.
1	3.	The high pressure chamber of claim 2 further comprising an o-ring within
2		the o-ring groove.
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1	4.	The high pressure chamber of claim 1 wherein the second sealing surface
2		of the platen comprises an o-ring groove.
1	5.	The high pressure chamber of claim 4 further comprising an o-ring within
2		the o-ring groove.
1	6.	The high pressure chamber of claim 1 wherein the first sealing surface of
2		the chamber housing seals to a spacer and further wherein the second sealing
3		surface of the platen seals to the spacer.

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1	7.	The high pressure chamber of claim 1 wherein the mechanical drive
2		mechanism comprises a piston driven by a fluid.
1	8.	The high pressure chamber of claim 7 wherein the fluid comprises an
2		incompressible fluid.
1	9.	The high pressure chamber of claim 7 wherein the fluid comprises a
2		compressible fluid.
1	10.	The high pressure chamber of claim 1 wherein the mechanical drive
2		mechanism comprises an electro-mechanical drive mechanism.
	11.	The high pressure chamber of claim 10 the electro-mechanical drive
		mechanism comprises a linear actuator.
	12.	The high pressure chamber of claim 11 wherein the linear actuator
		comprises a drive screw.
: E11	13.	The high pressure chamber of claim 1 further comprising a mechanical
11 <sup>2</sup>		clamp coupled to the chamber housing and the platen such that in operation the mechanical clamp maintains the high pressure processing chamber during
2 2 3 4 4		processing.
1	14.	A high pressure chamber for processing of a semiconductor substrate
2		comprising:
3		a. a chamber housing;
4		b. a platen comprising a region for holding the semiconductor
5		substrate;
6		c. a mechanical drive mechanism coupling the platen to the chamber
7		housing such that in operation the mechanical drive mechanism separates
8		the platen from the chamber housing for loading of the semiconductor
9		substrate; and

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